

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

## SSM6P16FE

High Speed Switching Applications

Analog Switch Applications

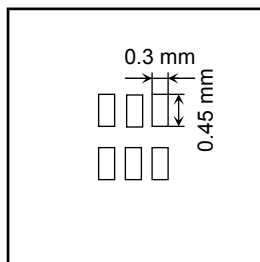
- Small package
- Low on-resistance :  $R_{on} = 8 \Omega$  (max) (@ $V_{GS} = -4 V$ )  
 :  $R_{on} = 12 \Omega$  (max) (@ $V_{GS} = -2.5 V$ )  
 :  $R_{on} = 45 \Omega$  (max) (@ $V_{GS} = -1.5 V$ )

### Absolute Maximum Ratings ( $T_a = 25^\circ C$ ) (Q1, Q2 Common)

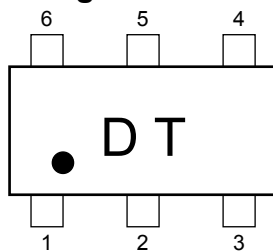
Characteristics		Symbol	Rating	Unit
Drain-Source voltage		$V_{DS}$	-20	V
Gate-Source voltage		$V_{GSS}$	$\pm 10$	V
Drain current	DC	$I_D$	-100	mA
	Pulse	$I_{DP}$	-200	
Drain power dissipation ( $T_a = 25^\circ C$ )		$P_D$ (Note 1)	150	mW
Channel temperature		$T_{ch}$	150	$^\circ C$
Storage temperature range		$T_{stg}$	-55~150	$^\circ C$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

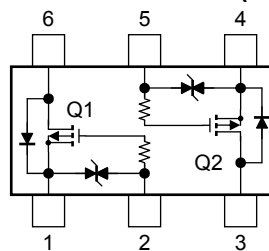
Note 1: Total rating, mounted on FR4 board  
 (25.4 mm  $\times$  25.4 mm  $\times$  1.6 t, Cu Pad: 0.135 mm<sup>2</sup>  $\times$  6)



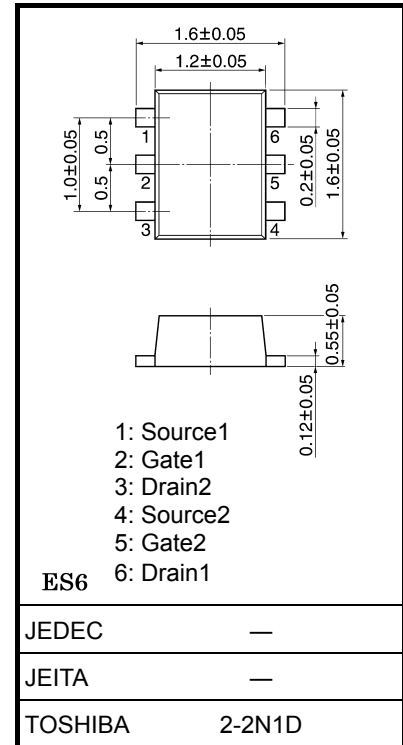
### Marking



### Equivalent Circuit (top view)



Unit: mm



### Handling Precaution

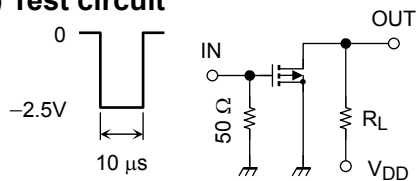
When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

## Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristic	Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT	
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	—	—	$\pm 1$	$\mu\text{A}$	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D = -0.1 \text{ mA}, V_{GS} = 0$	-20	—	—	V	
Drain cut-off current	$I_{DSS}$	$V_{DS} = -20 \text{ V}, V_{GS} = 0$	—	—	-1	$\mu\text{A}$	
Gate threshold voltage	$V_{th}$	$V_{DS} = -3 \text{ V}, I_D = -0.1 \text{ mA}$	-0.6	—	-1.1	V	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -3 \text{ V}, I_D = -10 \text{ mA}$	25	—	—	mS	
Drain-Source on-resistance	$R_{DS(ON)}$	$I_D = -10 \text{ mA}, V_{GS} = -4 \text{ V}$	—	6	8	$\Omega$	
		$I_D = -10 \text{ mA}, V_{GS} = -2.5 \text{ V}$	—	8	12		
		$I_D = -1 \text{ mA}, V_{GS} = -1.5 \text{ V}$	—	18	45		
Input capacitance	$C_{iss}$	$V_{DS} = -3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	11	—	pF	
Reverse transfer capacitance	$C_{rss}$		—	3.7	—	pF	
Output capacitance	$C_{oss}$		—	10	—	pF	
Switching time	Turn-on time	$t_{on}$	$V_{DD} = -3 \text{ V}, I_D = -10 \text{ mA},$ $V_{GS} = 0 \sim -2.5 \text{ V}$	—	130	—	ns
	Turn-off time	$t_{off}$		—	190	—	

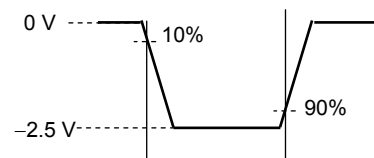
## Switching Time Test Circuit

### (a) Test circuit

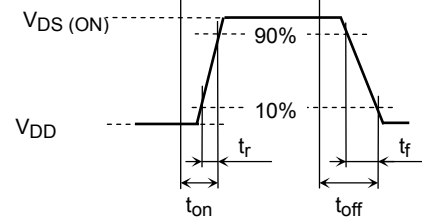


$V_{DD} = -3 \text{ V}$   
 Duty  $\leq 1\%$   
 $V_{IN}$ :  $t_r, t_f < 5 \text{ ns}$   
 ( $Z_{out} = 50 \Omega$ )  
 Common Source  
 $T_a = 25^\circ\text{C}$

### (b) $V_{IN}$



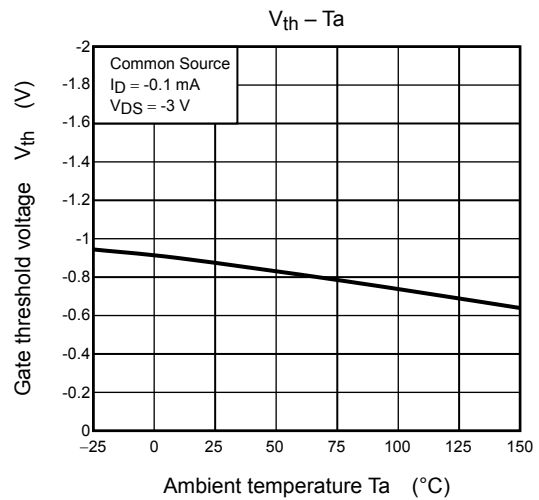
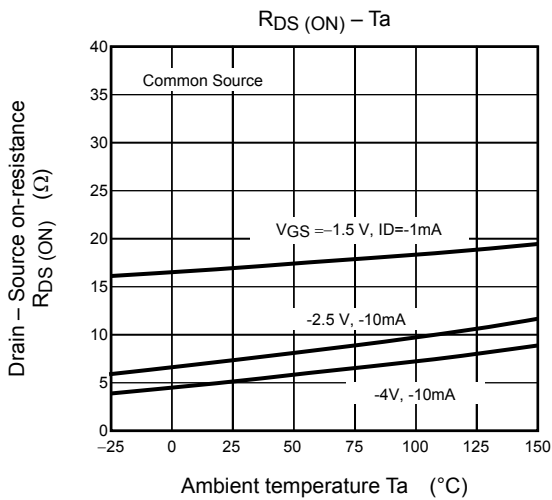
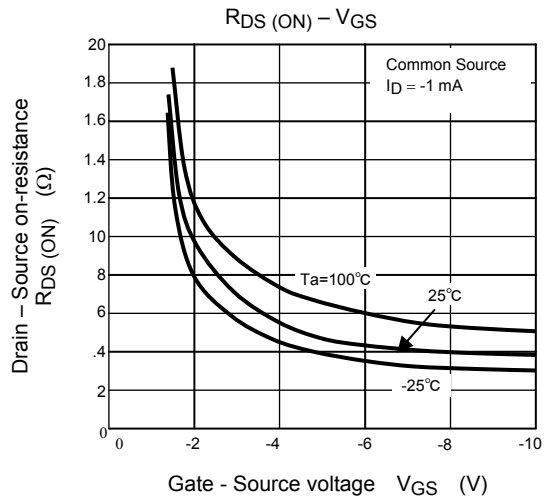
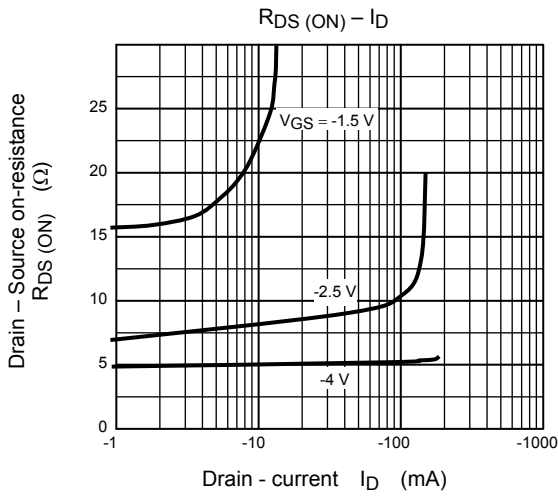
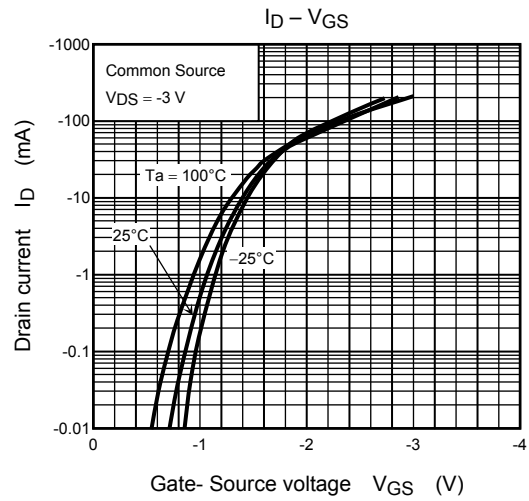
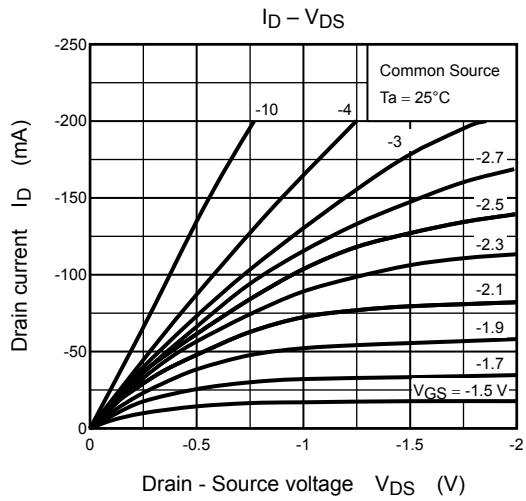
### (c) $V_{OUT}$

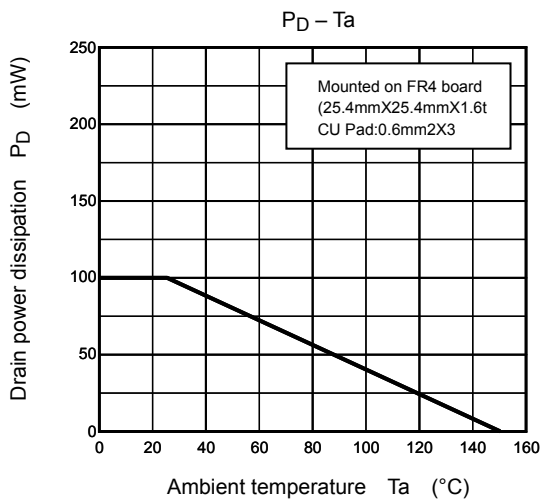
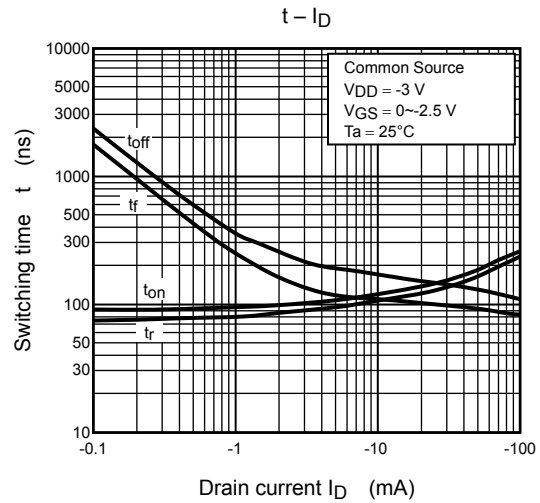
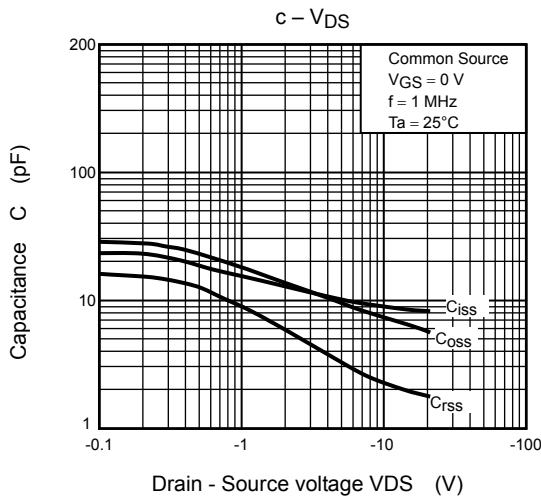
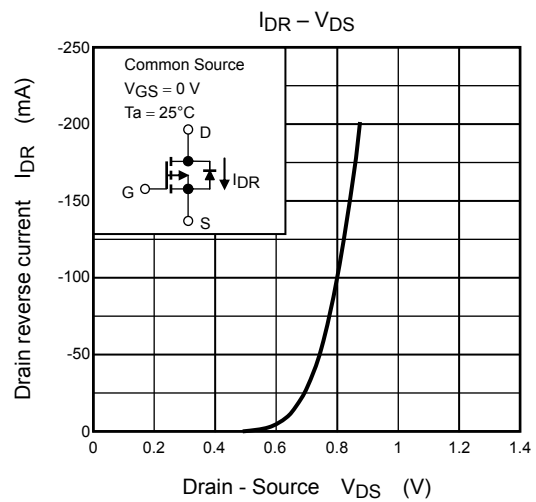
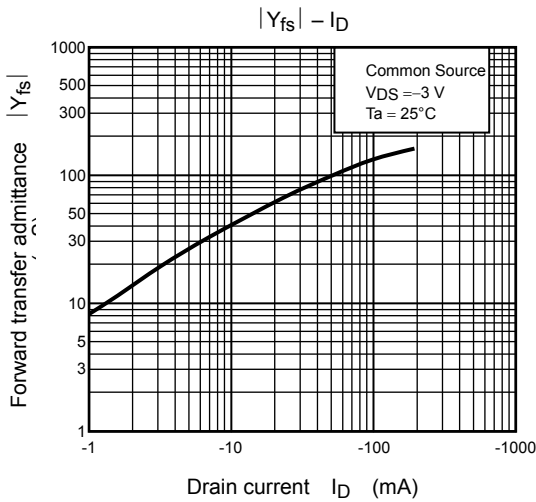


## Precaution

$V_{th}$  can be expressed as the voltage between the gate and source when the low operating current value is  $I_D = 100 \mu\text{A}$  for this product. For normal switching operation,  $V_{GS(on)}$  requires a higher voltage than  $V_{th}$  and  $V_{GS(off)}$  requires a lower voltage than  $V_{th}$ . (The relationship can be established as follows:  $V_{GS(off)} < V_{th} < V_{GS(on)}$ .)

Be sure to take this into consideration when using the device.





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20070701-EN GENERAL

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